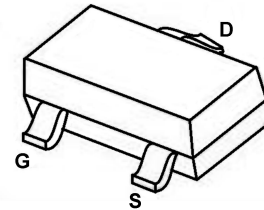


30V N-Channel MOSFET

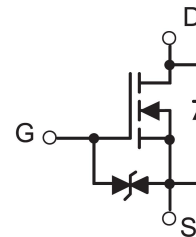
FEATURES

- Low on-resistance
- Fast switching speed
- Low voltage drive makes this device ideal for Portable equipment
- Easily designed drive circuits
- Easy to parallel

SOT-323



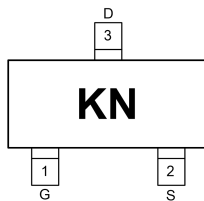
ELECTRICAL SYMBOL



Application

- Interfacing , Switching

MARKING



KN =Device Code

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	100	mA
Power Dissipation	P_D	0.2	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55~ +150	°C

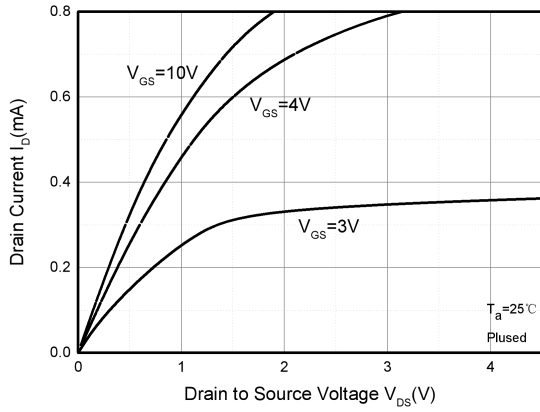
Electrical characteristics (TA=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 48V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 5	μA
Gate threshold voltage ¹⁾	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.8	1	1.45	V
Drain-source on-resistance ¹⁾	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 500mA$		1.5	3	Ω
		$V_{GS} = 4.5V, I_D = 200mA$		1.8	4	
Dynamic characteristics²⁾						
Input Capacitance	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$		27		pF
Output Capacitance	C_{oss}			13		
Reverse Transfer Capacitance	C_{rss}			6		
Switching Characteristics¹⁾²⁾						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 30V, I_D = 0.29A,$ $V_{GS} = 10V, R_G = 6\Omega$			5	nS
Rise time	t_r				18	
Turn-off delay time	$t_{d(off)}$				36	
Fall time	t_f				14	
Source-Drain Diode characteristics						
Diode Forward voltage	V_{SD}	$V_{GS} = 0V, I_S = 500mA$	0.5		1.4	V

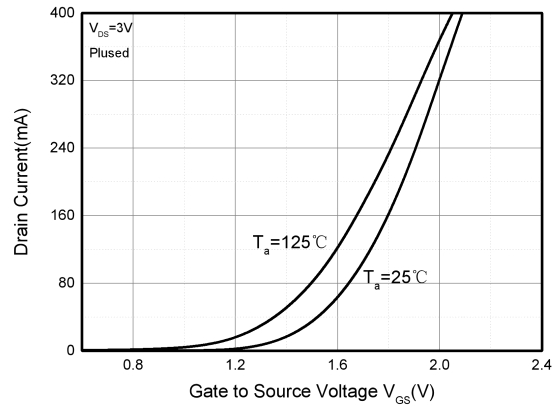
Notes:

- 1) Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- 2) These parameters have no way to verify.

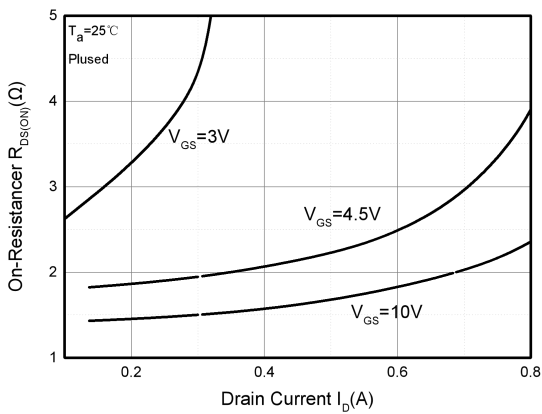
Typical Characteristics



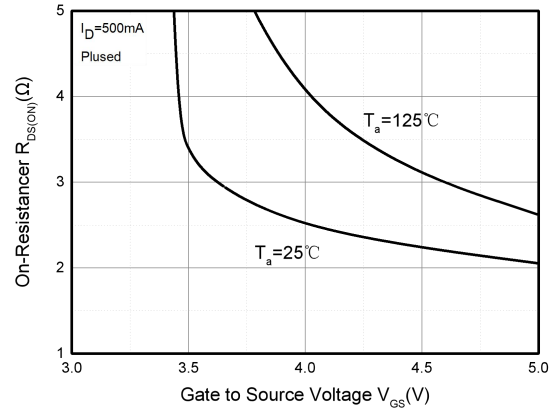
Output Characteristics



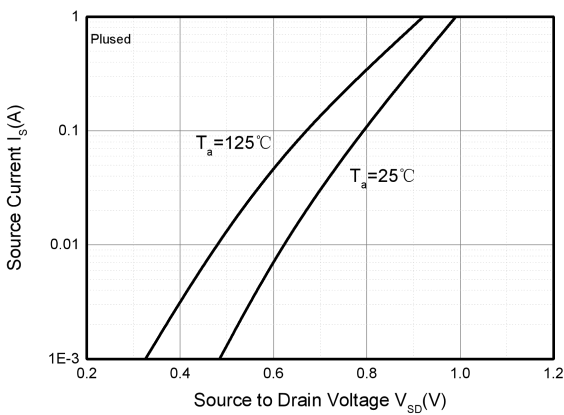
Transfer Characteristics



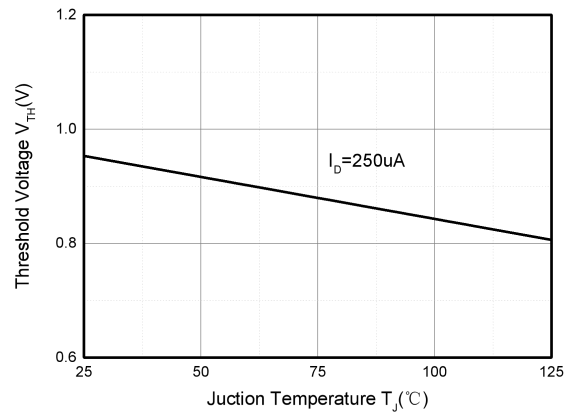
RDS(ON)—I_D



RDS(ON)—V_{GS}

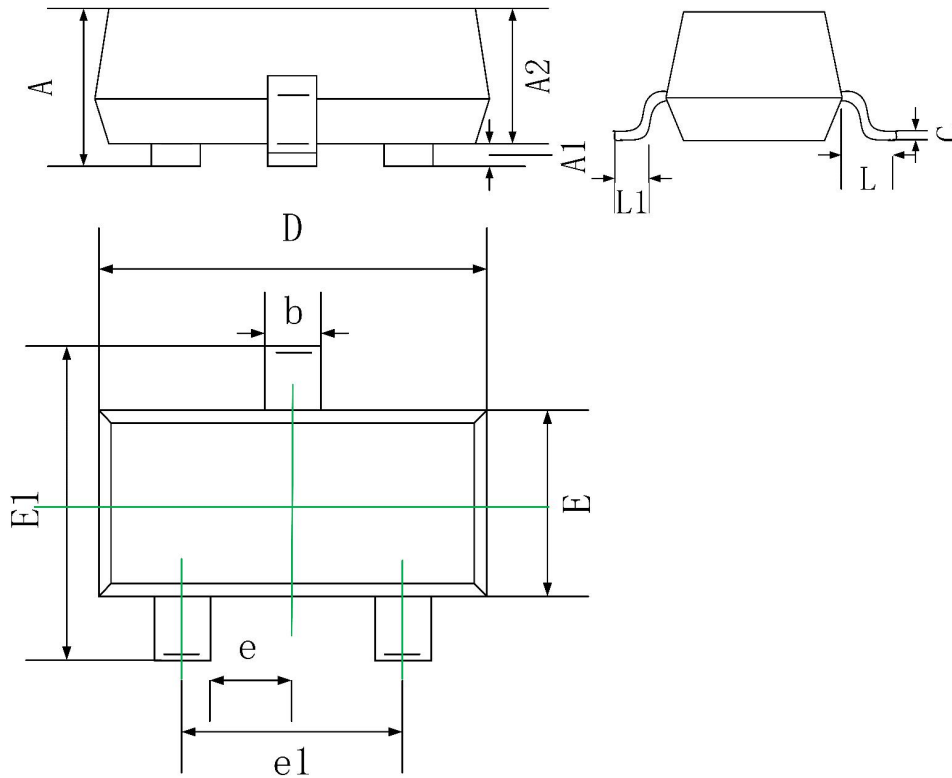


I_S—V_{SD}



Threshold Voltage

SOT-323 Package Outline Dimensions



SYM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.10	0.035	0.043
A1	0.00	0.10	0.000	0.004
A2	0.90	1.00	0.035	0.039
b	0.30	0.50	0.012	0.020
c	0.10	0.15	0.004	0.006
D	2.00	2.20	0.079	0.087
E	1.15	1.35	0.045	0.053
E1	2.15	2.40	0.085	0.094
e	0.65 TYP.		0.026 TYP.	
e1	1.20	1.40	0.047	0.055
L	0.525 REF.		0.002 REF.	
L1	0.26	0.46	0.010	0.018